

## 150V N-Ch Power MOSFET

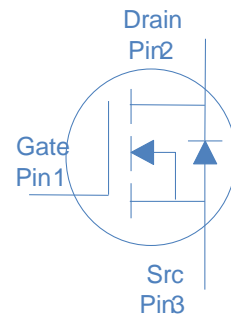
## Feature

- High Speed Power Switching Logic Level
- Enhanced Body diode dv/dt capability
- Enhanced Avalanche Ruggedness
- 100% UIS Tested 100% Rg Tested
- Lead Free

## Application

- Synchronous Rectification in SMPS
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$V_{DS}$		150	V
$R_{DS(on),typ}$	$V_{GS}=10V$	41	m :
$I_D$		28	A



Part Number	Package	Marking
HGD480N15M	TO-252	GD480N15M
HGI480N15M	TO-251	GI480N15M

Absolute Maximum Ratings at  $T_j=25$  (unless otherwise specified)

Parameter	Symbol	Conditions	Value	Unit
Continuous Drain Current	$I_D$	$T_C=25$	27.9	A
		$T_C=100$	19.7	
Drain to Source Voltage	$V_{DS}$	-	150	V
Gate to Source Voltage	$V_{GS}$	-	$\pm 20$	V
Pulsed Drain Current	$I_{DM}$	-	45	A
Avalanche Energy, Single Pulse	$E_{AS}$	$L=0.4mH, T_C=25$	20	mJ
Power Dissipation	$P_D$	$T_C=25$	83	W
Operating and Storage Temperature	$T_J, T_{stg}$	-	-55 to 175	

## Absolute Maximum Ratings

Parameter	Symbol	Max	Unit
Thermal Resistance Junction-Case	$R_{a-\&}$	1.8	/W
Thermal Resistance Junction-Ambient	$R_{a-\$}$	65	/W



Drain to Source on Resistance

$V_{DS}=5V, I_D=10A$

-  
-

41

Total Gate Charge

$Q_g (10V)$

Turn on Delay Time  
Rise time

$t_{d(on)}$   
 $t_r$   
 $t_{d(off)}$

3

$t_{rr}$

$V_R=75V, I_F=10A, dI_F/dt=100A/\mu s$

-  
-

0.9

Fig 1. Typical Output Characteristics

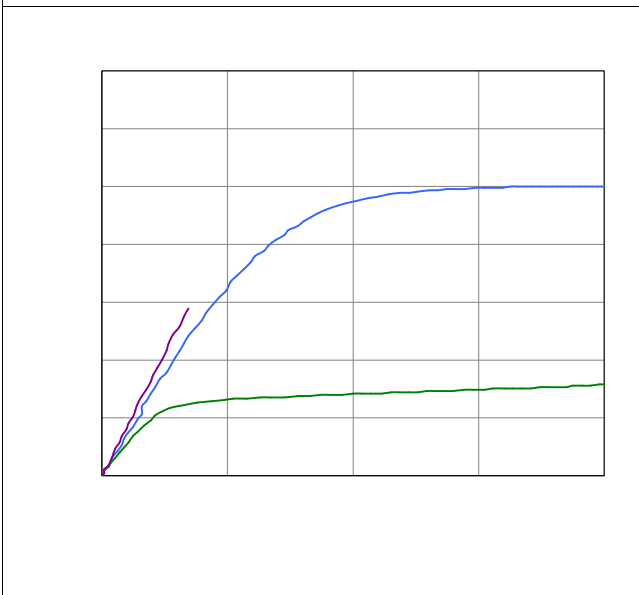


Figure 2. On-Resistance vs. Gate-Source Voltage

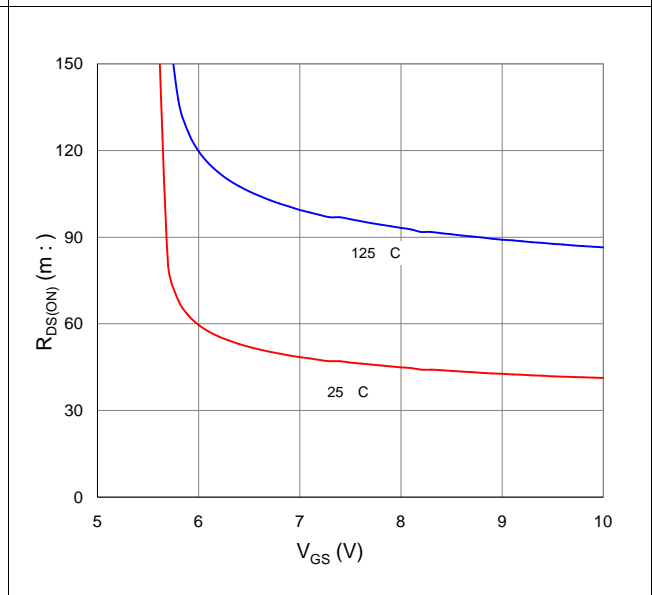


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

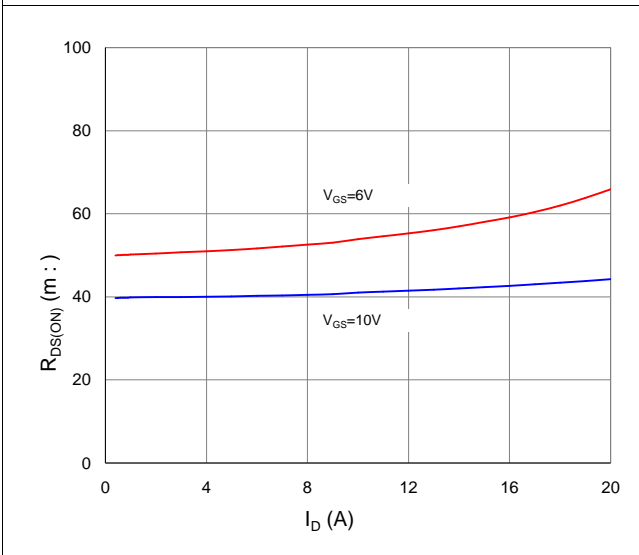


Figure 4. Normalized On-Resistance vs. Junction Temperature

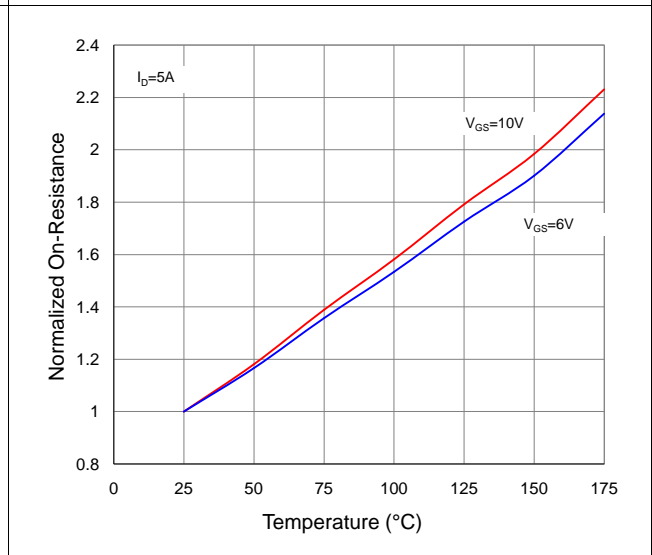


Figure 5. Typical Transfer Characteristics

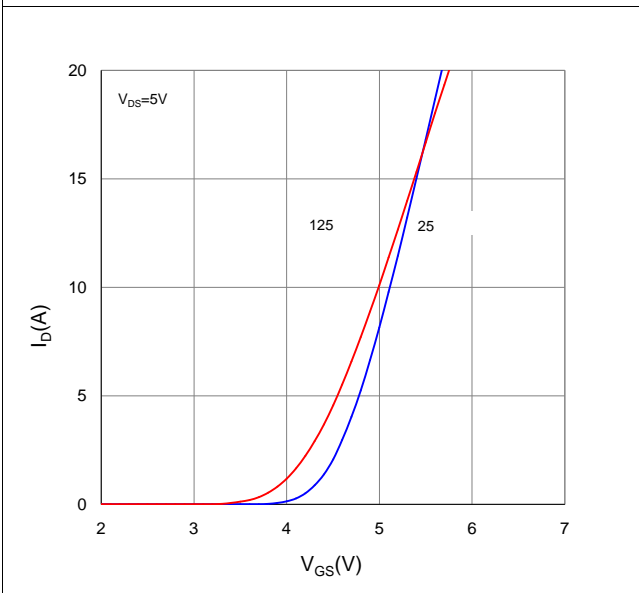


Figure 6. Typical Source-Drain Diode Forward Voltage

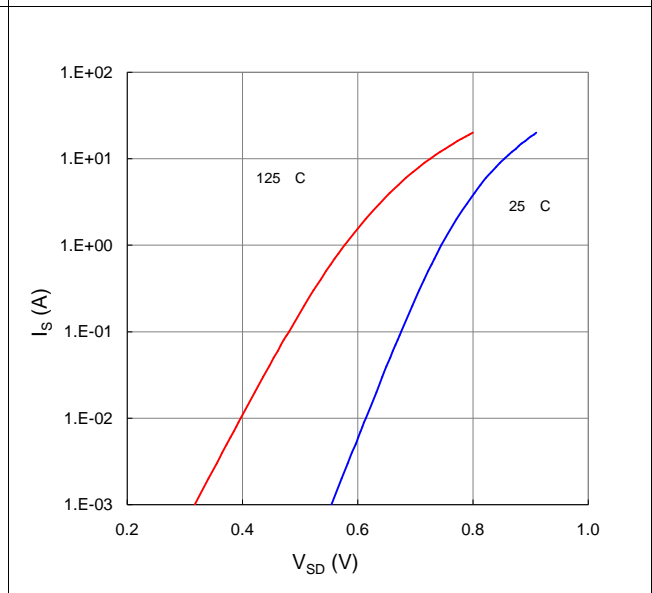


Figure 7. Typical Gate-Charge vs. Gate-to-Source Voltage

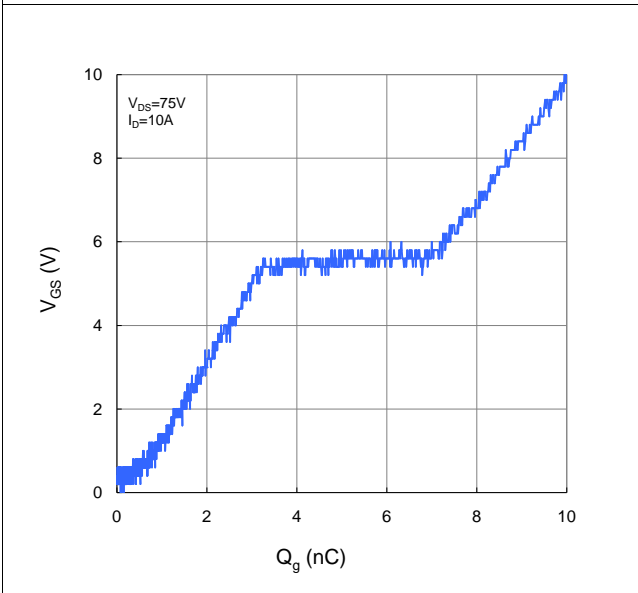


Figure 8. Typical Capacitance vs. Drain-to-Source Voltage

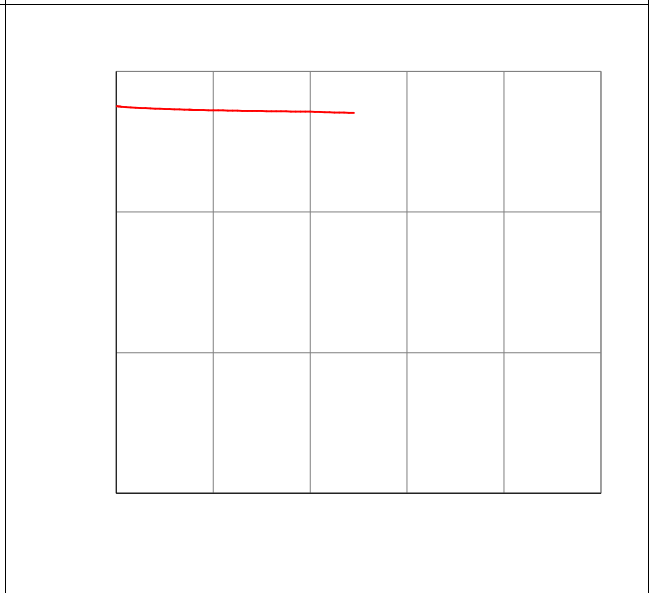


Figure 9. Maximum Safe Operating Area

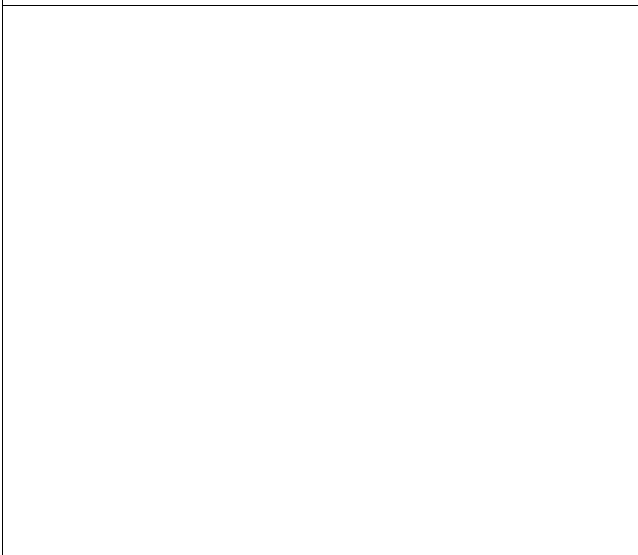


Figure 10. Maximun Drain Current vs. Case Temperature

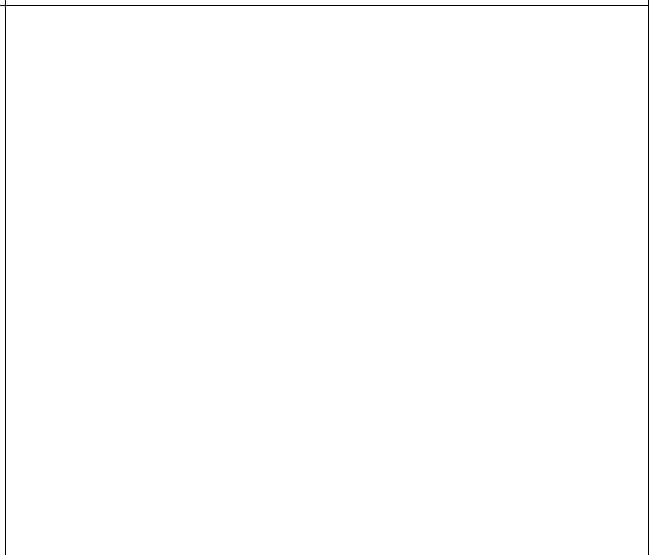
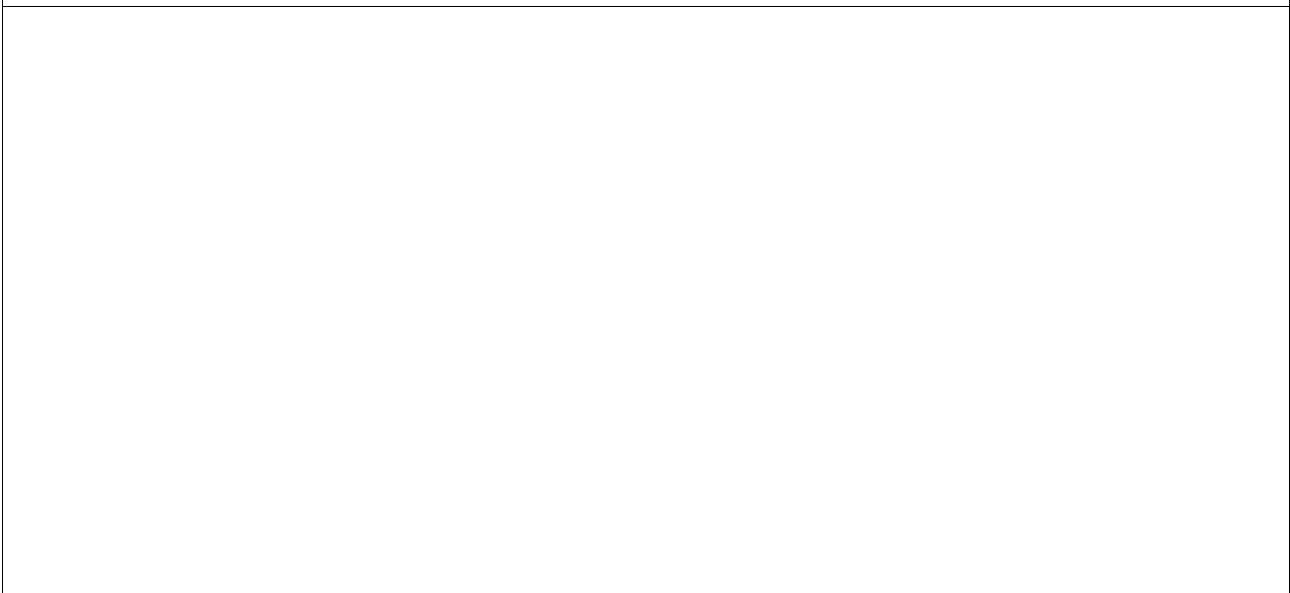


Figure 11. Normalized Maximum Transient Thermal Impedance, Junction-to-Case





TO-251, 3 leads

TO-252, 2 leads